

## **BUT11/11A**

## **High Voltage Power Switching Applications**



### **NPN Silicon Transistor**

1.Base 2.Collector 3.Emitter

# Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub> Collector-Base Voltage			V
	: BUT11	850	
	: BUT11A	1000	
V <sub>CEO</sub>	Collector-Emitter Voltage		V
	: BUT11	400	
	: BUT11A	450	
V <sub>EBO</sub>	Emitter-Base Voltage	9	V
I <sub>C</sub>	Collector Current (DC)	5	Α
I <sub>CP</sub>	*Collector Current (Pulse)	10	Α
I <sub>B</sub>	Base Current (DC)	2	Α
I <sub>BP</sub>	*Base Current (Pulse)	4	Α
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	100	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C

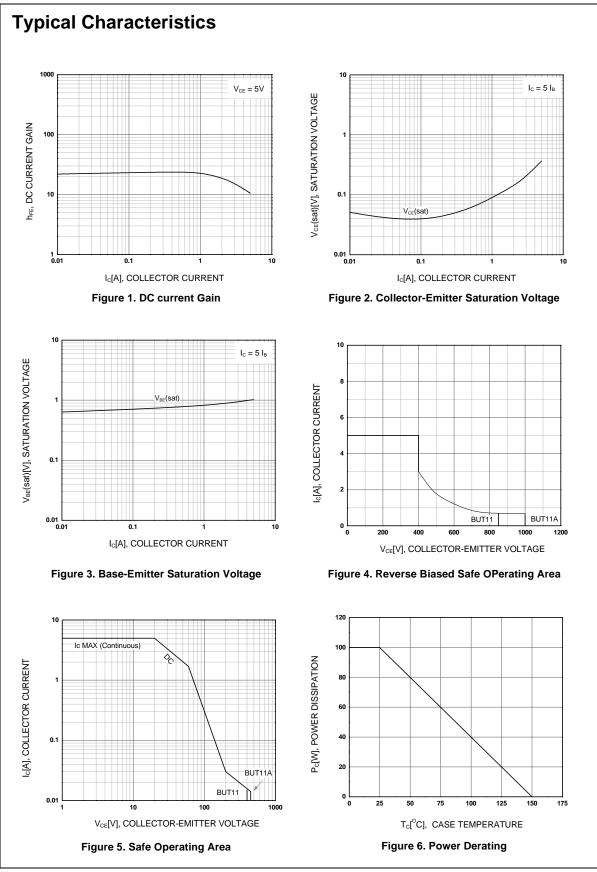
# Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V <sub>CEO</sub> (sus)	* Collector-Emitter Sustaining Voltage : BUT11 : BUT11A	I <sub>C</sub> = 100mA, I <sub>B</sub> = 0	400 450			V V
I <sub>CES</sub>	Collector Cut-off Current : BUT11 : BUT11A	V <sub>CE</sub> = 850V, V <sub>BE</sub> = 0			1	mA mA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{BE} = 9V, I_{C} = 0$			10	mA
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage : BUT11 : BUT11A	$I_C = 3A, I_B = 0.6A$ $I_C = 2.5A, I_B = 0.5A$			1.5 1.5	V V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage : BUT11 : BUT11A	$I_C = 3A, I_B = 0.6A$ $I_C = 2.5A, I_B = 0.5A$			1.3 1.3	V V
t <sub>ON</sub>	Turn On Time	$V_{CC} = 250V, I_{C} = 2.5A$			1	μs
t <sub>STG</sub>	Storage Time	$I_{B1} = -I_{B2} = 0.5A$			4	μs
t <sub>F</sub>	Fall Time	$R_L = 100\Omega$			0.8	μs

<sup>\*</sup> Pulsed: pulsed duration = 300μs, duty cycle = 1.5%

### Thermal Characteristics $T_C=25$ °C unless otherwise noted

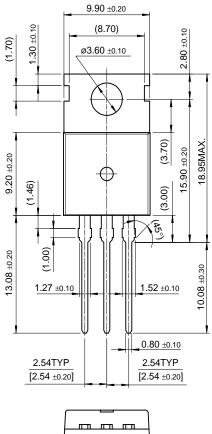
Symbol	Parameter	Тур	Max	Units
$R_{\theta jC}$	Thermal Resistance, Junction to Case		1.25	°C/W

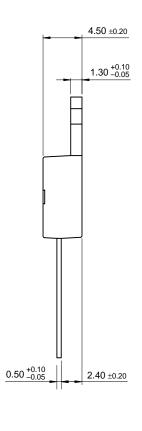


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# **Package Demensions**

# TO-220





10.00 ±0.20

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